

# **BCR30CM-8LB**

400V-30A-Triac

Medium Power Use

R07DS1105EJ0100 Rev.1.00 Aug 08, 2013

#### **Features**

•  $I_{T (RMS)} : 30 A$  $V_{DRM}$ : 400 V

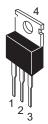
 $I_{FGT I}$ ,  $I_{RGT I}$ ,  $I_{RGT III}$ : 30 mA

- Tj: 150 °C
- Planar Passivation Type
- Non-Insulated Type

#### **Outline**

RENESAS Package code: PRSS0004AG-A

(Package name: TO-220AB)





- T<sub>1</sub> Terminal
   T<sub>2</sub> Terminal
   Gate Terminal

- 4. T<sub>2</sub> Terminal

## **Applications**

Vacuum cleaner, electric heater, light dimmer, copying machine, and other general controlling devices

## **Maximum Ratings**

Parameter	Symbol	Voltage class	Unit	
Farameter	Syllibol	8		
Repetitive peak off-state voltage <sup>Note1</sup>	$V_{DRM}$	400	V	
Non-repetitive peak off-state voltage <sup>Note1</sup>	$V_{DSM}$	500	V	

Parameter	Symbol	Ratings	Unit	Conditions
RMS on-state current	I <sub>T(RMS)</sub>	30	A	Commercial frequency, sine full wave 360° conduction, Tc = 107°C <sup>Note3</sup>
Surge on-state current	I <sub>TSM</sub>	300	A	60Hz sinewave 1 full cycle, peak value, non-repetitive
I <sup>2</sup> t for fusing	l <sup>2</sup> t	450	A <sup>2</sup> s	Value corresponding to 1 cycle of half wave 60Hz, surge on-state current
Peak gate power dissipation	$P_{GM}$	5	W	
Average gate power dissipation	$P_{G(AV)}$	0.5	W	
Peak gate voltage	$V_{GM}$	10	V	
Peak gate current	$I_{GM}$	2	Α	
Junction temperature	Tj	- 40 to +150	°C	
Storage temperature	Tstg	- 40 to +150	°C	
Mass	_	2.1	g	Typical value

## **Electrical Characteristics**

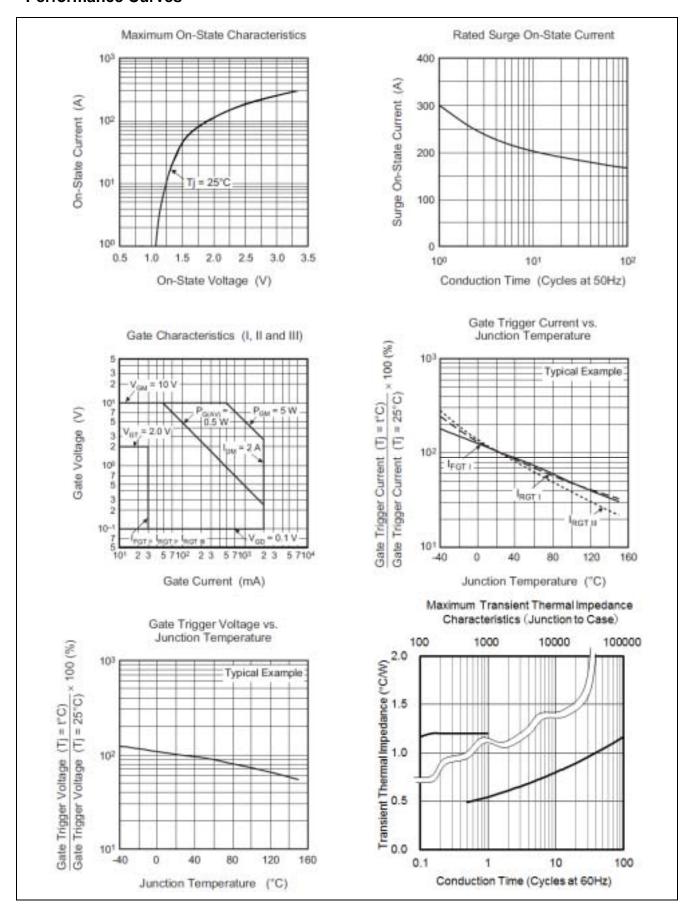
Parameter		Symbol	Min.	Тур.	Max.	Unit	Test conditions
Repetitive peak off-state cur	rent	$I_{DRM}$	_	_	3.0	mA	Tj = 125°C, V <sub>DRM</sub> applied
			_	_	5.0	mA	Tj = 150°C, V <sub>DRM</sub> applied
On-state voltage		$V_{TM}$	_	_	1.5	V	$Tc = 25^{\circ}C, I_{TM} = 45 A,$
							Instantaneous measurement
Gate trigger voltage <sup>Note2</sup>	I	$V_{FGT\ I}$	_	_	2.0	V	$Tj = 25$ °C, $V_D = 6$ V, $R_L = 6$ $\Omega$ ,
	II	$V_{RGTI}$	_	_	2.0	V	$R_G = 330 \Omega$
	III	$V_{RGTIII}$	_	_	2.0	V	
Gate trigger current <sup>Note2</sup>	I	I <sub>FGT I</sub>	_	_	30	mA	$Tj = 25^{\circ}C, V_D = 6 V, R_L = 6 \Omega,$
	II	$I_{RGT\;I}$	_	_	30	mA	$R_G = 330 \Omega$
	III	I <sub>RGT III</sub>	_	_	30	mA	
Gate non-trigger voltage		$V_{GD}$	0.2	_	_	V	$Tj = 125$ °C, $V_D = 1/2 V_{DRM}$
			0.1	_	_	V/μs	$Tj = 150$ °C, $V_D = 1/2 V_{DRM}$
Thermal resistance		R <sub>th(j-c)</sub>	_	_	1.1	°C/W	Junction to case <sup>Note3 Note4</sup>
Critical-rate of rise of off-stat	te	(dv/dt)c	10	_	_	V/μs	Tj = 125°C
commutating voltage <sup>Note5</sup>			1	_	_	V/μs	Tj = 150°C

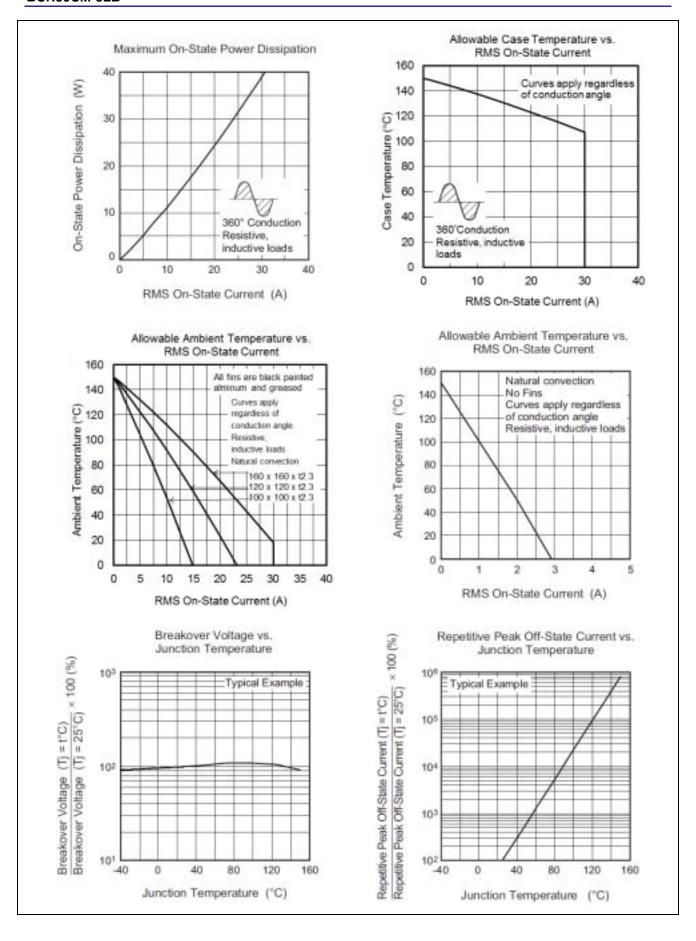
Notes: 1. Gate open.

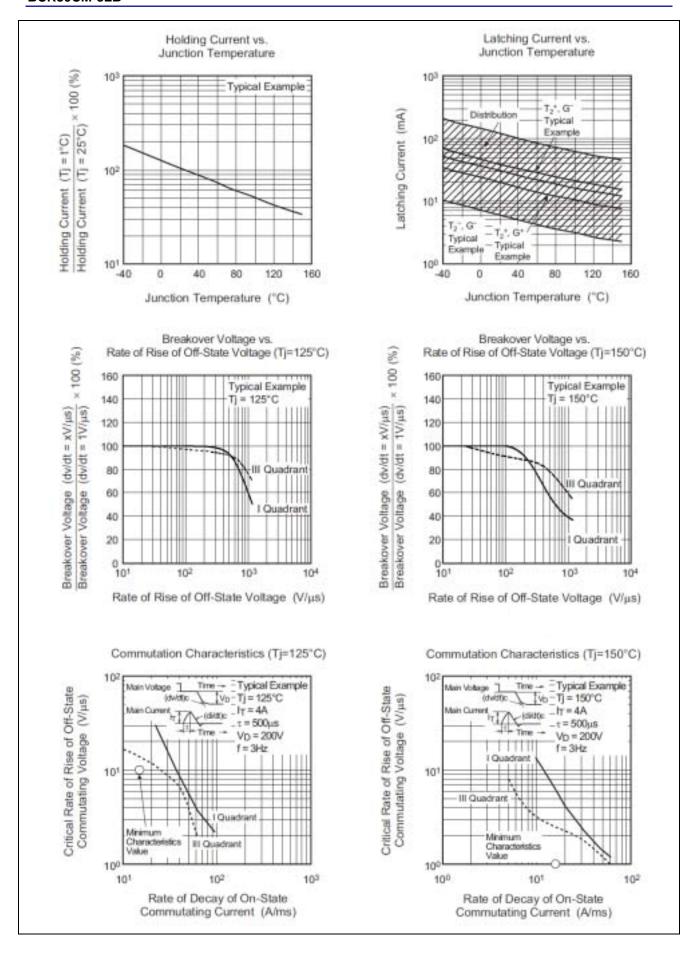
- 2. Measurement using the gate trigger characteristics measurement circuit.
- 3. Case temperature is measured at the  $T_2$  tab 1.5 mm apart from the molded case.
- 4. The contact thermal resistance  $R_{th\;(c\text{-}f)}$  in case of greasing is 1.0°C /W.
- 5. Test conditions of the critical-rate of rise of off-state commutation voltage is shown in the table below.

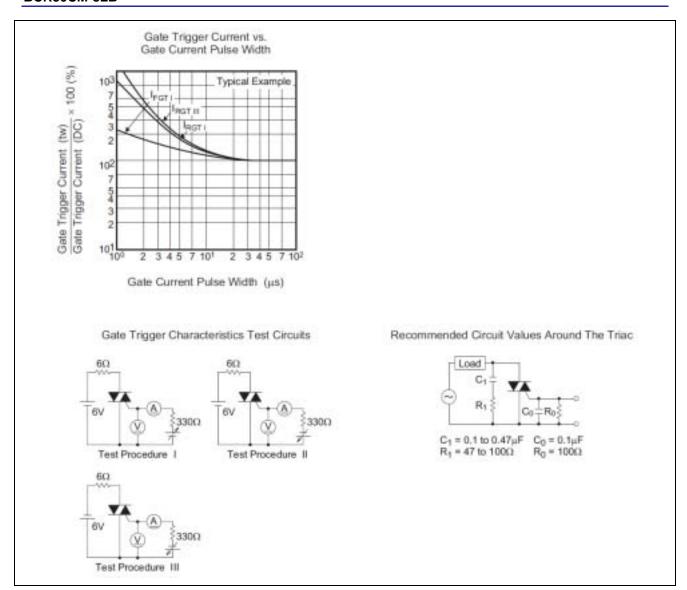
Test conditions	Commutating voltage and current waveforms (inductive load)
1. Junction temperature Tj = 125/150°C	Supply Voltage
2. Peak off-state voltage  V <sub>D</sub> = 400 V  3. Rate of decay of on-state commutating current  (di/dt)c = -16 A/ms	Main Current  Main Voltage  (di/dt)c  Time  (dv/dt)c

#### **Performance Curves**

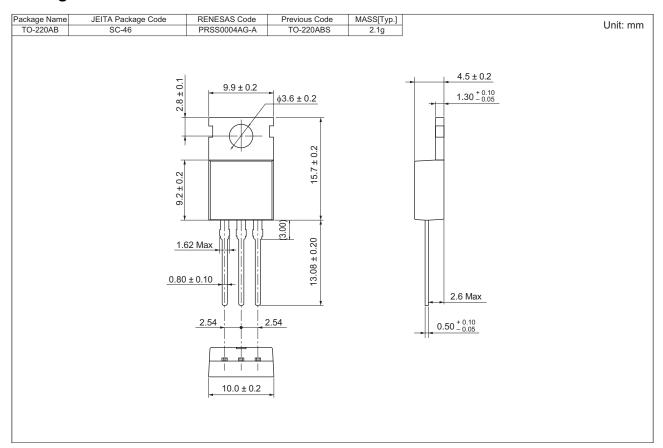








## **Package Dimensions**



# **Ordering Information**

Orderable Part Number	Packing	Quantity	Remark
BCR30CM-8LB#BB0	Tube	50 pcs.	Straight type
BCR30CM-8LB-A8#BB0	Tube	50 pcs.	A8 Lead form

Note: Please confirm the specification about the shipping in detail.

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